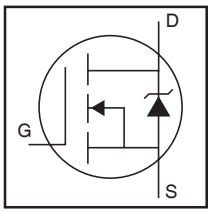
International
IOR Rectifier

PD - 97263

IRF1324S-7PPbF

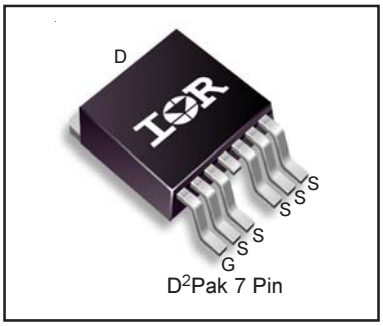
HEXFET® Power MOSFET

Applications
- High Efficiency Synchronous Rectification in SMPS
- Uninterruptible Power Supply
- High Speed Power Switching
- Hard Switched and High Frequency Circuits



V_{DSS}	24V
$R_{DS(on)}$ typ.	0.8mΩ
max.	1.0mΩ
I_D	429A

Benefits
- Improved Gate, Avalanche and Dynamic dV/dt Ruggedness
- Fully Characterized Capacitance and Avalanche SOA
- Enhanced body diode dV/dt and dI/dt Capability
- Lead-Free



D^2Pak 7 Pin

G	D	S
Gate	Drain	Source

Absolute Maximum Ratings

Symbol	Parameter	Max.	Units
I_D @ T_C = 25°C	Continuous Drain Current, V_{GS} @ 10V	429①	A
I_D @ T_C = 100°C	Continuous Drain Current, V_{GS} @ 10V	303①	
I_{DM}	Pulsed Drain Current ②	1640	
P_D @T_C = 25°C	Maximum Power Dissipation	300	W
	Linear Derating Factor	2.0	W/°C
V_{GS}	Gate-to-Source Voltage	± 20	V
dv/dt	Peak Diode Recovery ④	1.6	V/ns
T_J T_{STG}	Operating Junction and Storage Temperature Range	-55 to + 175	°C
	Soldering Temperature, for 10 seconds (1.6mm from case)	300	
	Mounting torque, 6-32 or M3 screw	10lb·in (1.1N·m)	

Avalanche Characteristics

$E_{AS\ (Thermally\ limited)}$	Single Pulse Avalanche Energy ③	230	mJ
I_{AR}	Avalanche Current ①	See Fig. 14, 15, 22a, 22b,	A
E_{AR}	Repetitive Avalanche Energy ⑤		mJ

Thermal Resistance

Symbol	Parameter	Typ.	Max.	Units
$R_{\theta JC}$	Junction-to-Case ⑨	—	0.50	°C/W
$R_{\theta JA}$	Junction-to-Ambient (PCB Mount) , D^2Pak ⑧⑨	—	40	

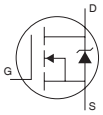
Static @ T_J = 25°C (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Units	Conditions
$V_{(BR)DSS}$	Drain-to-Source Breakdown Voltage	24	—	—	V	V_{GS} = 0V, I_D = 250µA
$\Delta V_{(BR)DSS}/\Delta T_J$	Breakdown Voltage Temp. Coefficient	—	0.023	—	V/°C	Reference to 25°C, I_D = 5mA②
$R_{DS(on)}$	Static Drain-to-Source On-Resistance	—	0.80	1.0	mΩ	V_{GS} = 10V, I_D = 160A ⑤
$V_{GS(th)}$	Gate Threshold Voltage	2.0	—	4.0	V	V_{DS} = V_{GS}, I_D = 250µA
I_{DSS}	Drain-to-Source Leakage Current	—	—	20	µA	V_{DS} = 24V, V_{GS} = 0V
		—	—	250		V_{DS} = 19V, V_{GS} = 0V, T_J = 125°C
I_{GSS}	Gate-to-Source Forward Leakage	—	—	200	nA	V_{GS} = 20V
	Gate-to-Source Reverse Leakage	—	—	-200		V_{GS} = -20V
R_G	Internal Gate Resistance	—	3.0	—	Ω	

Dynamic @ T_J = 25°C (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Units	Conditions
gfs	Forward Transconductance	270	—	—	S	V_{DS} = 50V, I_D = 160A
Q_g	Total Gate Charge	—	180	252	nC	I_D = 75A
Q_{gs}	Gate-to-Source Charge	—	47	—		V_{DS} =12V
Q_{gd}	Gate-to-Drain ("Miller") Charge	—	58	—		V_{GS} = 10V ⑤
Q_{sync}	Total Gate Charge Sync. (Q_g - Q_{gd})	—	122	—		I_D = 75A, V_{DS} =0V, V_{GS} = 10V ⑤
$t_{d(on)}$	Turn-On Delay Time	—	19	—	ns	V_{DD} = 16V
t_r	Rise Time	—	240	—		I_D = 160A
$t_{d(off)}$	Turn-Off Delay Time	—	86	—		R_G =2.7Ω
t_f	Fall Time	—	93	—		V_{GS} = 10V ⑤
C_{iss}	Input Capacitance	—	7700	—	pF	V_{GS} = 0V
C_{oss}	Output Capacitance	—	3380	—		V_{DS} = 19V
C_{rss}	Reverse Transfer Capacitance	—	1930	—		f = 1.0MHz, See Fig.5
C_{oss} eff. (ER)	Effective Output Capacitance (Energy Related)	—	4780	—		V_{GS} = 0V, V_{DS} = 0V to 19V ⑦, See Fig.11
C_{oss} eff. (TR)	Effective Output Capacitance (Time Related)⑥	—	4970	—		V_{GS} = 0V, V_{DS} = 0V to 19V ⑥

Diode Characteristics

Symbol	Parameter	Min.	Typ.	Max.	Units	Conditions
I_S	Continuous Source Current (Body Diode)	—	—	429①	A	MOSFET symbol showing the integral reverse p-n junction diode. 
I_{SM}	Pulsed Source Current (Body Diode) ②	—	—	1636	A	
V_{SD}	Diode Forward Voltage	—	—	1.3	V	T_J = 25°C, I_S = 160A, V_{GS} = 0V ⑤
t_{rr}	Reverse Recovery Time	—	71	107	ns	T_J = 25°C V_R = 20V,
		—	74	110		T_J = 125°C I_F = 160A
Q_{rr}	Reverse Recovery Charge	—	83	120	nC	T_J = 25°C di/dt = 100A/µs ⑤
		—	92	140		T_J = 125°C
I_{RRM}	Reverse Recovery Current	—	2.0	—	A	T_J = 25°C
t_{on}	Forward Turn-On Time	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

Notes:

① Calculated continuous current based on maximum allowable junction temperature. Package limitation current is 160A.

② Repetitive rating; pulse width limited by max. junction temperature.

③ Limited by T_{Jmax}, starting T_J = 25°C, L = 0.018mH R_G = 25Ω, I_{AS} = 160A, V_{GS} =10V. Part not recommended for use above this value.

④ I_{SD} ≤ 160A, di/dt ≤ 600A/µs, V_{DD} ≤ $V_{(BR)DSS}$, T_J ≤ 175°C.

⑤ Pulse width ≤ 400µs; duty cycle ≤ 2%.

⑥ C_{oss} eff. (TR) is a fixed capacitance that gives the same charging time as C_{oss} while V_{DS} is rising from 0 to 80% V_{DSS}.

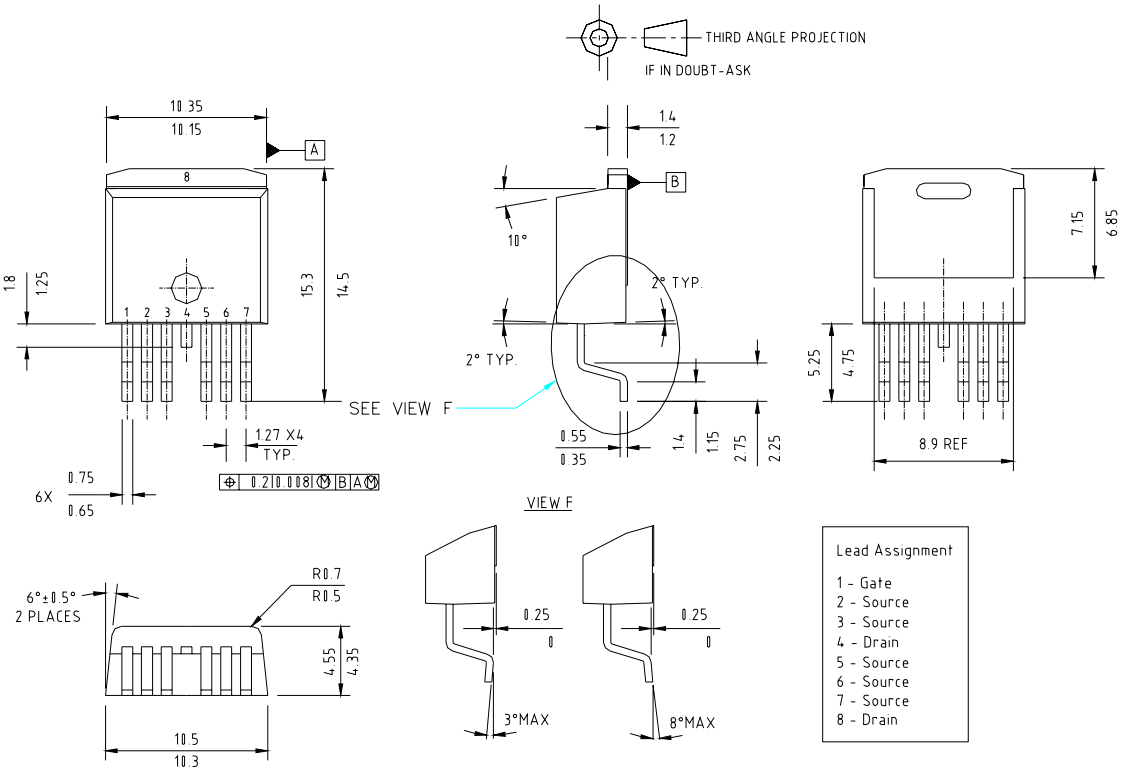
⑦ C_{oss} eff. (ER) is a fixed capacitance that gives the same energy as C_{oss} while V_{DS} is rising from 0 to 80% V_{DSS}.

⑧ When mounted on 1" square PCB (FR-4 or G-10 Material). For recommended footprint and soldering techniques refer to application note #AN-994.

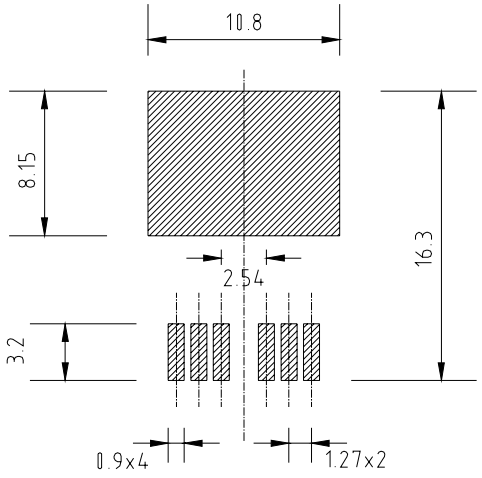
⑨ R_θ is measured at T_J approximately 90°C

D²Pak - 7 Pin Package Outline

Dimensions are shown in millimeters (inches)



RECOMMENDED FOOTPRINT

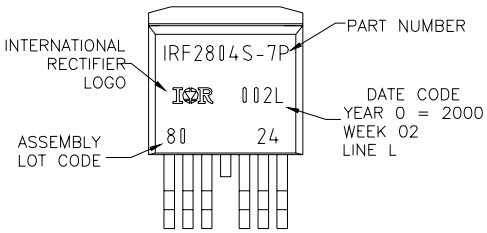


REV	DATE	MODIFICATION
-	18/03/03	RAISED IAW ECN 3426
Rev1	07/04/03	CHANGED IAW ECN 3438
A	23/04/04	ADD LEAD ASSIGNMENT

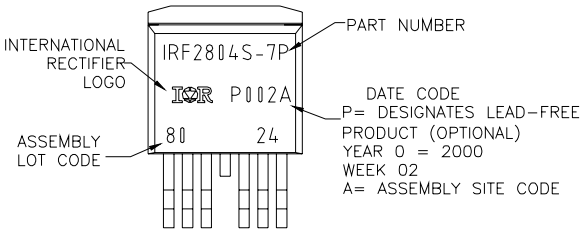
D²Pak - 7 Pin Part Marking Information

EXAMPLE: THIS IS AN IRF2804S-7P WITH
LOT CODE 8024
ASSEMBLED ON WW02,2000
IN THE ASSEMBLY LINE "L"

Note: "P" in assembly line
position indicates "Lead Free"



OR

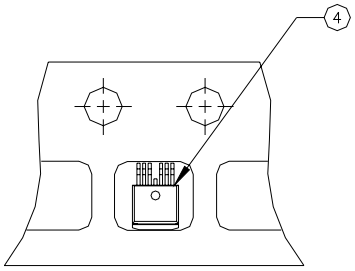


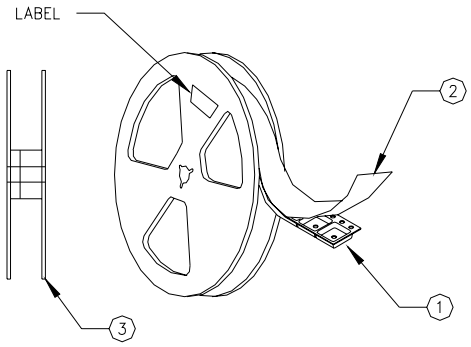
D²Pak - 7 Pin Tape and Reel

NOTES, TAPE & REEL, LABELLING:

1. TAPE AND REEL.
   - 1.1 REEL SIZE 13 INCH DIAMETER.
   - 1.2 EACH REEL CONTAINING 800 DEVICES.
   - 1.3 THERE SHALL BE A MINIMUM OF 42 SEALED POCKETS CONTAINED IN THE LEADER AND A MINIMUM OF 15 SEALED POCKETS IN THE TRAILER.
   - 1.4 PEEL STRENGTH MUST CONFORM TO THE SPEC. NO. 71-9667.
   - 1.5 PART ORIENTATION SHALL BE AS SHOWN BELOW.
   - 1.6 REEL MAY CONTAIN A MAXIMUM OF TWO UNIQUE LOT CODE/DATE CODE COMBINATIONS. REWORKED REELS MAY CONTAIN A MAXIMUM OF THREE UNIQUE LOT CODE/DATE CODE COMBINATIONS. HOWEVER, THE LOT CODES AND DATE CODES WITH THEIR RESPECTIVE QUANTITIES SHALL APPEAR ON THE BAR CODE LABEL FOR THE AFFECTED REEL.

2. LABELLING (REEL AND SHIPPING BAG).
   - 2.1 CUST. PART NUMBER (BAR CODE): IRFXXXXSTRL-7P
   - 2.2 CUST. PART NUMBER (TEXT CODE): IRFXXXXSTRL-7P
   - 2.3 I.R. PART NUMBER: IRFXXXXSTRL-7P
   - 2.4 QUANTITY:
   - 2.5 VENDOR CODE: IR
   - 2.6 LOT CODE:
   - 2.7 DATE CODE:





Data and specifications subject to change without notice.
This product has been designed and qualified for the Industrial market.